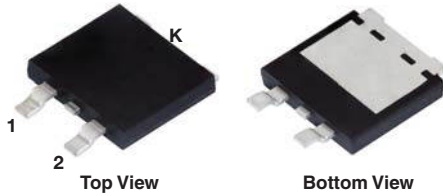
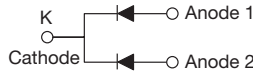


## Hyperfast Rectifier, 2 x 8 A FRED Pt®


**TO-263AC (SMPD)**


### FEATURES

- Hyperfast recovery time, reduced  $Q_{rr}$ , and soft recovery
- 175 °C maximum operating junction temperature
- Specified for output and snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)


**RoHS**  
 COMPLIANT  
 HALOGEN  
**FREE**

### DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, telecom, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

PRODUCT SUMMARY	
Package	TO-263AC (SMPD)
$I_{F(AV)}$	2 x 8 A
$V_R$	200 V
$V_F$ at $I_F$	0.77 V
$t_{rr}$	27 ns
$T_J$ max.	175 °C
Diode variation	Dual die

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage	$V_{RRM}$		200	V
Average rectified forward current	$I_{F(AV)}$	$T_{\text{solder pad}} = 155\text{ °C}$	16	A
			8	
Non-repetitive peak surge current	$I_{FSM}$	$T_J = 25\text{ °C}$ , 6 ms square pulse	190	
			100	

ELECTRICAL SPECIFICATIONS ( $T_J = 25\text{ °C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	$V_{BR}, V_R$	$I_R = 100\ \mu\text{A}$	200	-	-	V
		$I_F = 8\text{ A}$	-	0.93	1.03	
Forward voltage, per diode	$V_F$	$I_F = 8\text{ A}, T_J = 150\text{ °C}$	-	0.77	0.87	
		$V_R = V_R$ rated	-	-	2	
Reverse leakage current, per diode	$I_R$	$T_J = 150\text{ °C}, V_R = V_R$ rated	-	6	100	$\mu\text{A}$
			-	-	-	
Junction capacitance, per diode	$C_T$	$V_R = 200\text{ V}$	-	23	-	pF

DYNAMIC RECOVERY CHARACTERISTICS (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Reverse recovery time	t <sub>rr</sub>	I <sub>F</sub> = 1 A, dI <sub>F</sub> /dt = 50 A/μs, V <sub>R</sub> = 30 V	-	27	-	ns
		I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1 A, I <sub>rr</sub> = 0.25 A	-	-	25	
		T <sub>J</sub> = 25 °C	-	23	-	
		T <sub>J</sub> = 125 °C	-	35	-	
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C	-	2.8	-	A
		T <sub>J</sub> = 125 °C	-	5	-	
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C	-	30	-	nC
		T <sub>J</sub> = 125 °C	-	90	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	+175	°C
Thermal resistance, per diode junction to solder pad	R <sub>thJ-Sp</sub>		-	1.8	2.5	°C/W
Approximate weight			0.55			g
			0.02			oz.
Marking device		Case style TO-263AC (SMPD)	16CDH02			

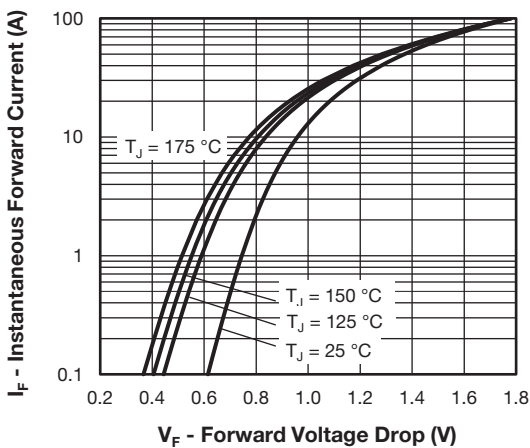


Fig. 1 - Typical Forward Voltage Drop Characteristics

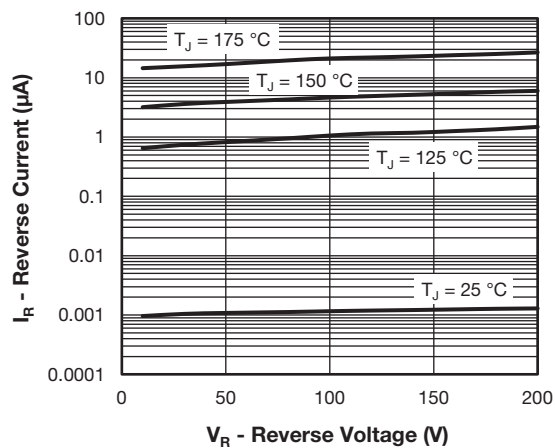


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

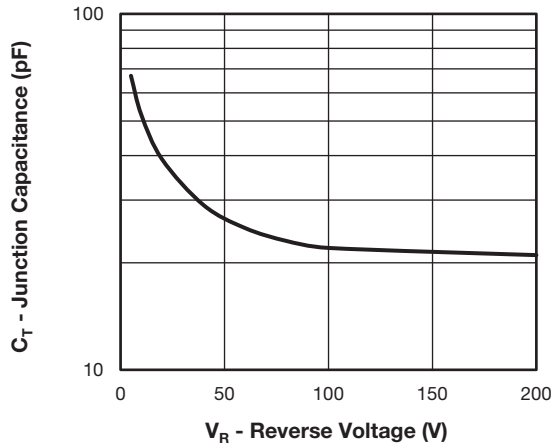


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

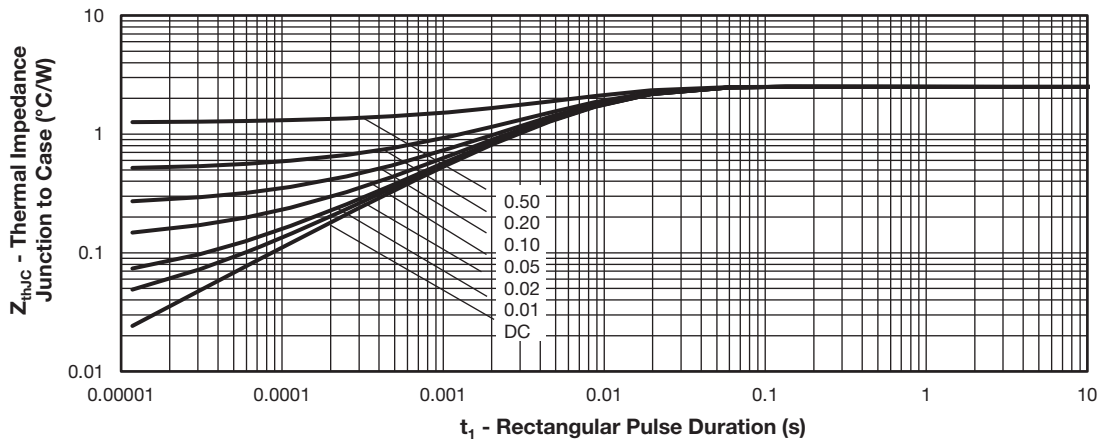


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics

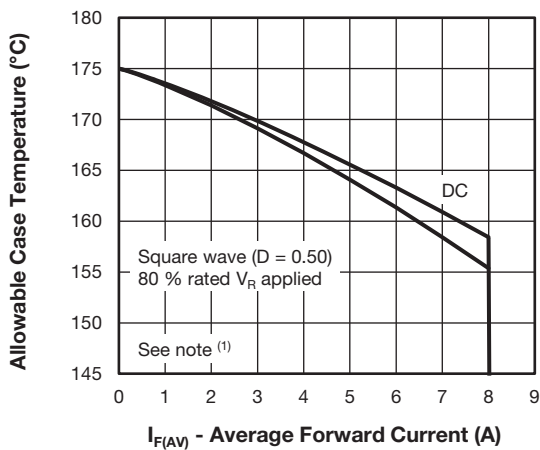


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

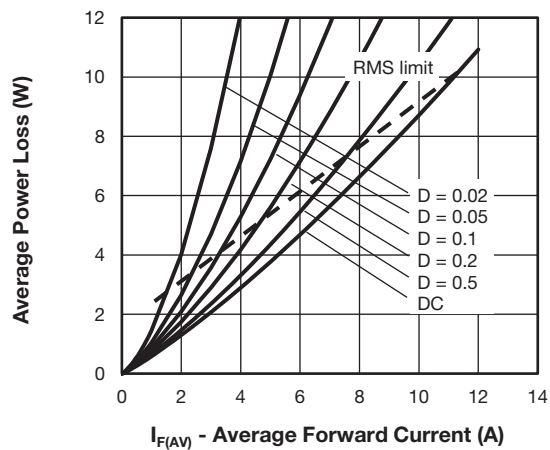


Fig. 6 - Forward Power Loss Characteristics

**Note**

- (1) Formula used:  $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$ ;
- $P_d$  = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 5);
- $P_{dREV}$  = Inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1}$  = rated  $V_R$

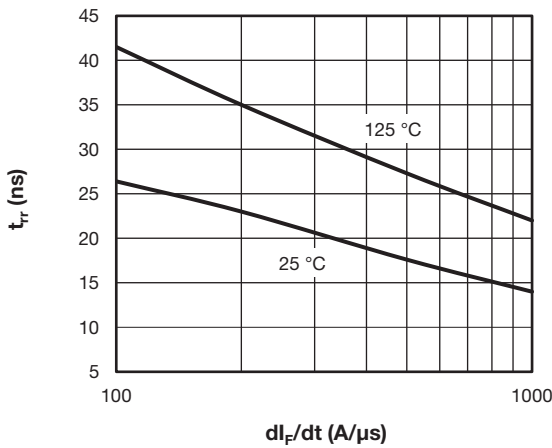


Fig. 7 - Typical Reverse Recovery Time vs.  $di_F/dt$

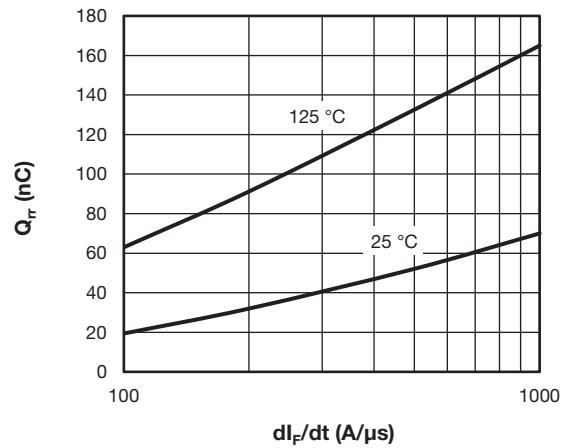
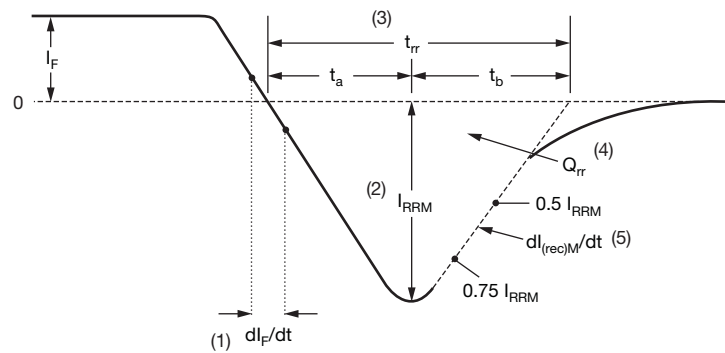


Fig. 8 - Typical Stored Charge vs.  $di_F/dt$



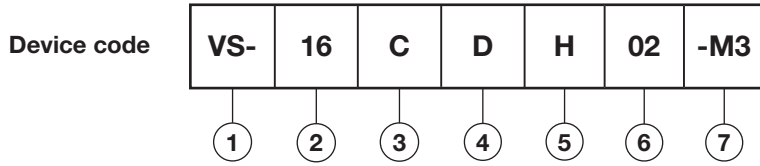
- (1)  $di_F/dt$  - rate of change of current through zero crossing
- (2)  $I_{RRM}$  - peak reverse recovery current
- (3)  $t_{rr}$  - reverse recovery time measured from zero crossing point of negative going  $I_F$  to point where a line passing through  $0.75 I_{RRM}$  and  $0.50 I_{RRM}$  extrapolated to zero current.
- (4)  $Q_{rr}$  - area under curve defined by  $t_{rr}$  and  $I_{RRM}$
- (5)  $dl_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

Fig. 9 - Reverse Recovery Waveform and Definitions



**ORDERING INFORMATION TABLE**



- ① - Vishay Semiconductors product
- ② - Current rating (16 A)
- ③ - Circuit configuration:  
C = common cathode
- ④ - D = SMPD package
- ⑤ - Process type,  
H = hyperfast recovery
- ⑥ - Voltage code (02 = 200 V)
- ⑦ - -M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

<b>ORDERING INFORMATION</b> (Example)			
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-16CDH02-M3/I	2000	2000	13" diameter plastic tape and reel

<b>LINKS TO RELATED DOCUMENTS</b>	
Dimensions	<a href="http://www.vishay.com/doc?95604">www.vishay.com/doc?95604</a>
Part marking information	<a href="http://www.vishay.com/doc?95566">www.vishay.com/doc?95566</a>
Packaging information	<a href="http://www.vishay.com/doc?88869">www.vishay.com/doc?88869</a>



## TO-263AC (SMPD)

**DIMENSIONS** in inches (millimeters)





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